2MBI1800XXG170-50

IGBT Modules

Power Module (X series)
1700V / 1800A / 2-in-1 package

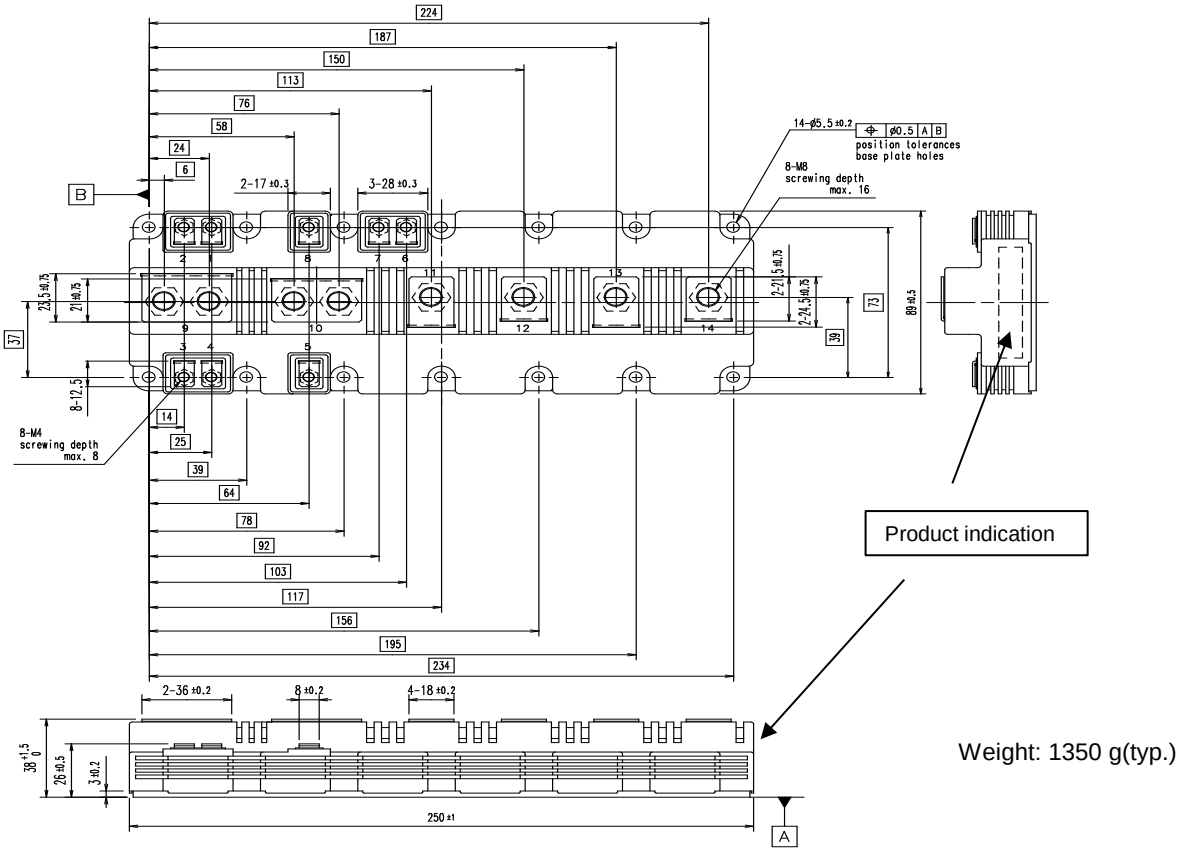
■ Features

Low $V_{CE(sat)}$
Low Inductance Module structure

■ Applications

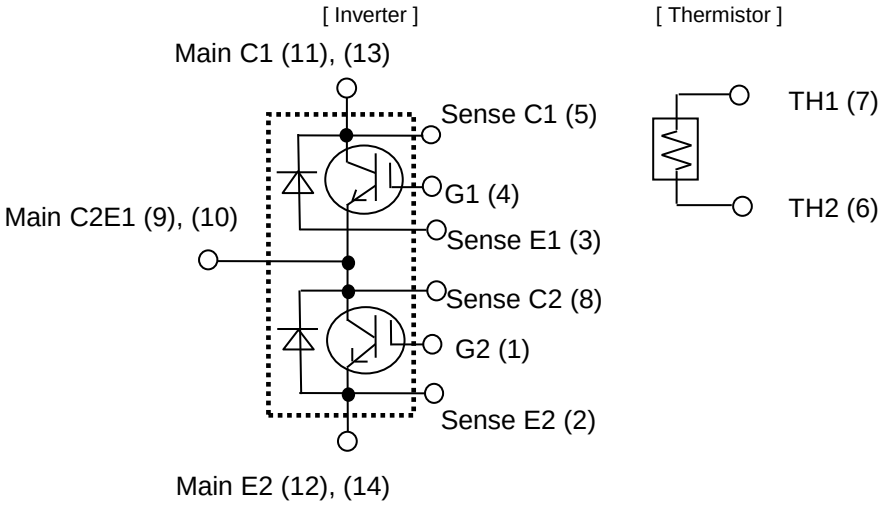
Inverter for Motor Drives, AC and DC Servo Drives
Uninterruptible Power Supply Systems, Wind Turbines, PV Power Conditioning Systems

■ Outline drawing (Unit : mm)



Weight: 1350 g(typ.)

■ Equivalent Circuit



FM5F9461
2019/07

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■ Absolute Maximum Ratings (at T_C= 25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum Ratings	Units
Inverter	Collector-emitter voltage, gate-emitter short-circuited	V_{CES}			1700	V
	Gate-emitter voltage, collector-emitter short-circuited	V_{GES}			±20	V
	Collector-emitter voltage, gate-emitter short-circuited	I_C	Continuous	T_C=100°C	1800	A
	Repetitive peak collector current	I_{CRM}	1ms		3600	
	Forward current	I_F			1800	
	Repetitive peak forward current	I_{FRM}	1ms		3600	
	Total power dissipation	P_{tot}	1 device		13	W
	Virtual junction temperature	T_{vj}			175	°C
	Operating virtual junction temperature (under switching conditions)	T_{vjop}			175	
Case temperature		T_c			150	
Storage temperature		T_{stg}			-40 ~ 150	
Isolation voltage	between terminals and copper base (*1)	V_{isol}	AC: 1min.		4000	Vrms
	between thermistor and others (*2)					
Mounting torque of screws to heatsink (*3)		M_s	M5		6.0	N·m
Mounting torque of screws to main terminals (*3)		M_t	M8		10.0	
Mounting torque of screws to sense terminals (*3)			M4		2.1	

(*1) All terminals should be connected together during the test.

(*2) Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

(*3) Recommendable Value: : Mounting torque of screws to heatsink 3.0 ~ 6.0 N·m (M5)
: Mounting torque of screws to main terminals 8.0~ 10.0 N·m (M8)
: Mounting torque of screws to sense terminals 1.8~ 2.1 N·m (M4)

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■ Electrical characteristics (at T_{vj}= 25°C unless otherwise specified)

	Items	Symbols	Conditions		Characteristics min.	Characteristics typ.	Characteristics max.	Units
Inverter	Collector-Emitter cut-off current, gate-emitter short-circuited	I_{CES}	V_{GE} = 0V V_{CE} = 1700V		-	-	600	μA
	Gate-Emitter leakage current	I_{GES}	V_{CE}=0V, V_{GE}=±20V		-	-	1200	nA
	Gate-Emitter threshold voltage	$V_{GE(th)}$	V_{CE} = 20V I_C = 1800mA		6.0	6.5	7.0	V
	Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	V_{GE} = 15V I_C= 1800A	T_{vj}=25°C	-	1.75	2.20	V
		$V_{CE(sat)}$ (chip)		T_{vj}=25°C	-	1.70	2.15	
				T_{vj}=125°C	-	2.10	-	
				T_{vj}=150°C	-	2.20	-	
				T_{vj}=175°C	-	2.30	-	
	Internal gate resistance	r_g	-		-	2.08	-	Ω
	Capacitance	C_{ies}	V_{CE}=10V, V_{GE}=0V, f=1MHz		-	280	-	nF
		C_{oes}			-	7.3	-	
		C_{res}			-	2.2	-	
	Gate charge	Q_G	V_{CC} = 900V, I_C = 1800A V_{GE} = -15 → +15V		-	14.3	-	μC
	Forward voltage	V_F (terminal)	V_{GE} = 0V I_F= 1800A	T_{vj}=25°C	-	1.80	2.25	V
		V_F (chip)		T_{vj}= 25°C	-	1.75	2.20	
				T_{vj}=125°C	-	1.90	-	
				T_{vj}=150°C	-	1.90	-	
				T_{vj}=175°C	-	1.95	-	
	Switching time (*1)	$t_{d(on)}$	V_{CC} = 900V I_C, I_F = 1800A V_{GE} = ±15V R_G = +0.22/-0.68Ω L_S = 40 nH	T_{vj}= 25°C	-	1.11	-	μs
				T_{vj}=125°C	-	1.09	-	
				T_{vj}=150°C	-	1.09	-	
				T_{vj}=175°C	-	1.09	-	
		t_r		T_{vj}= 25°C	-	0.16	-	
				T_{vj}=125°C	-	0.18	-	
				T_{vj}=150°C	-	0.18	-	
				T_{vj}=175°C	-	0.18	-	
		$t_{d(off)}$		T_{vj}= 25°C	-	1.02	-	
				T_{vj}=125°C	-	1.07	-	
				T_{vj}=150°C	-	1.09	-	
				T_{vj}=175°C	-	1.10	-	
		t_f		T_{vj}= 25°C	-	0.20	-	
				T_{vj}=125°C	-	0.44	-	
				T_{vj}=150°C	-	0.50	-	
				T_{vj}=175°C	-	0.56	-	
	Reverse recovery time	t_{rr}		T_{vj}= 25°C	-	0.38	-	
				T_{vj}=125°C	-	0.52	-	
				T_{vj}=150°C	-	0.56	-	
				T_{vj}=175°C	-	0.60	-	

(*1) Turn on time (t_{on}) = $t_{d(on)}$+ t_r , Turn off time (t_{off}) = $t_{d(off)}$ + t_f

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■ Electrical characteristics (at T_{vj}= 25°C unless otherwise specified)

Items		Symbols	Conditions		Characteristics min.	Characteristics typ.	Characteristics max.	Units
Inverter	Switching loss (per pulse)	E_{on}	V_{CC} = 900V, I_C, I_F = 1800A, V_{GE} = ±15V, R_G = +0.22/-0.68Ω, L_S = 40 nH	T_{vj}= 25°C	-	424	-	mJ
				T_{vj}=125°C	-	540	-	
				T_{vj}=150°C	-	574	-	
				T_{vj}=175°C	-	612	-	
		E_{off}		T_{vj}= 25°C	-	459	-	
				T_{vj}=125°C	-	585	-	
				T_{vj}=150°C	-	621	-	
				T_{vj}=175°C	-	651	-	
		E_{rr}		T_{vj}= 25°C	-	284	-	
				T_{vj}=125°C	-	410	-	
				T_{vj}=150°C	-	464	-	
				T_{vj}=175°C	-	517	-	
Thermistor	Resistance	R	T =	25°C	-	5000	-	Ω
			T =	100°C	465	495	520	
	B value	B	T =	25/ 50°C	3305	3375	3450	K

NOTICE:
The external gate resistance (R_G) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum R_G depends on circuit configuration and/or environment. We recommend that the R_G has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

■Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics min.	Characteristics typ.	Characteristics max.	Units
Thermal resistance (1 device)	$R_{th(j-c)}$	Inverter IGBT	-	-	11.5	K/kW
		Inverter FWD	-	-	22.0	
Thermal resistance (1 IGBT+1 FWD) (*1)	$R_{th(c-s)}$	with 1 W/(m·K) thermal grease	-	4.2	-	

(*1) This is the value which is defined mounting on the additional heatsink with thermal grease.

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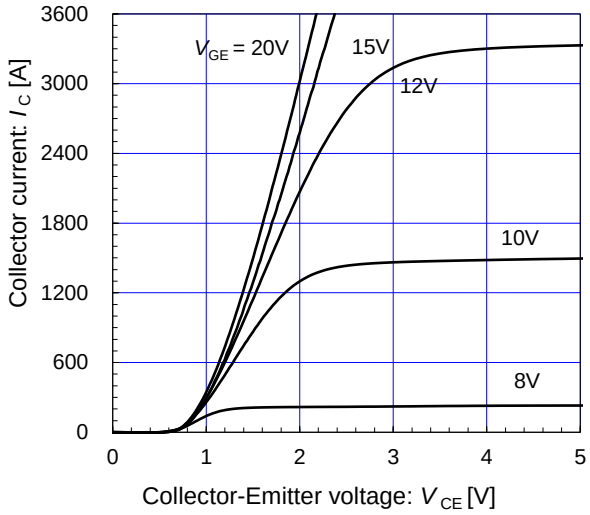
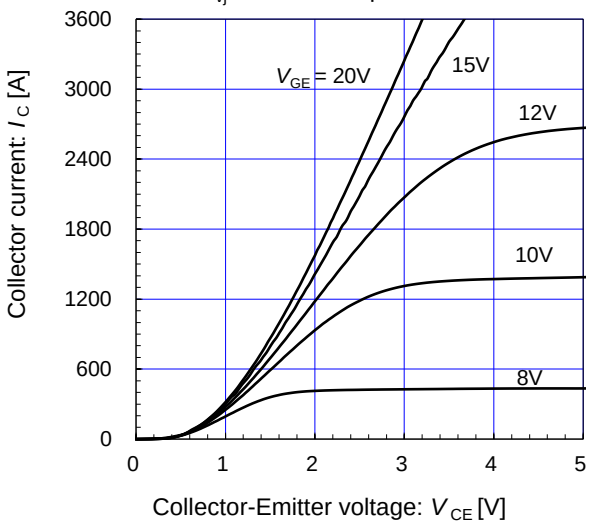
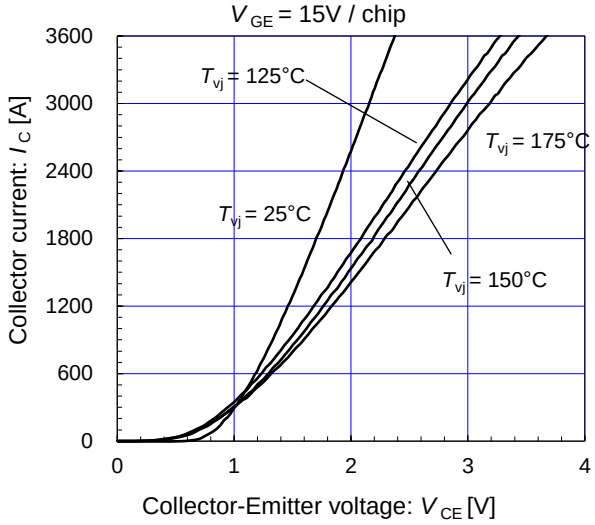
[Inverter]
Collector current vs. Collector-Emitter voltage
T_{vj} = 25°C / chip



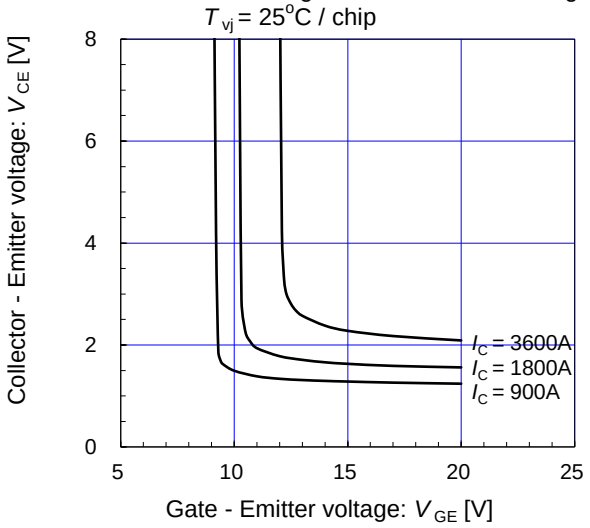
[Inverter]
Collector current vs. Collector-Emitter voltage (typ.)
T_{vj} = 175°C / chip



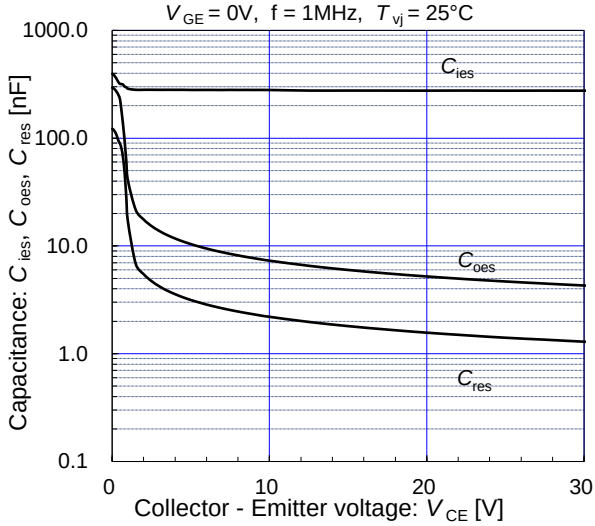
[Inverter]
Collector current vs. Collector-Emitter voltage
V_{GE} = 15V / chip



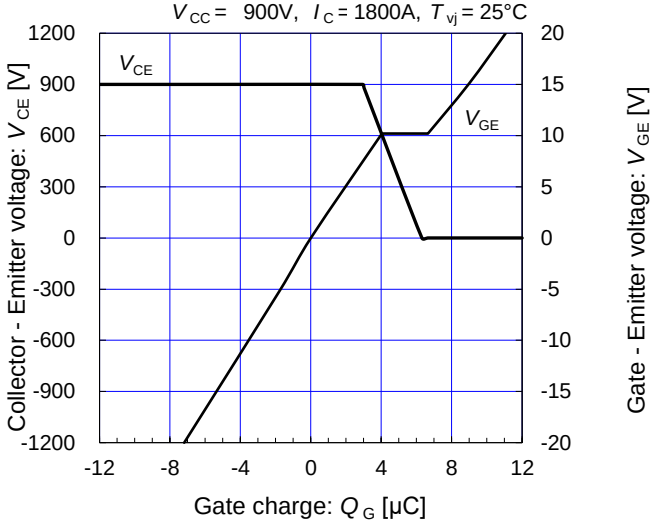
[Inverter]
Collector-emitter voltage vs. Gate-Emitter voltage
T_{vj} = 25°C / chip



[Inverter]
Capacitance vs. Collector-Emitter voltage
V_{GE} = 0V, f = 1MHz, T_{vj} = 25°C



[Inverter]
Dynamic Gate Charge (typ.)
V_{CC} = 900V, I_C = 1800A, T_{vj} = 25°C



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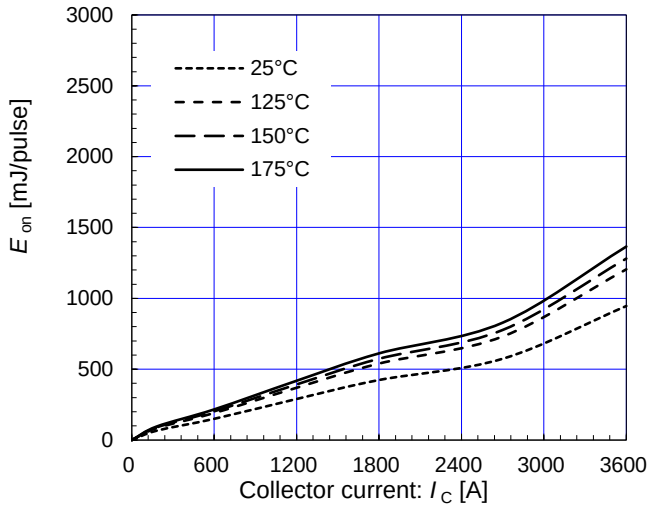
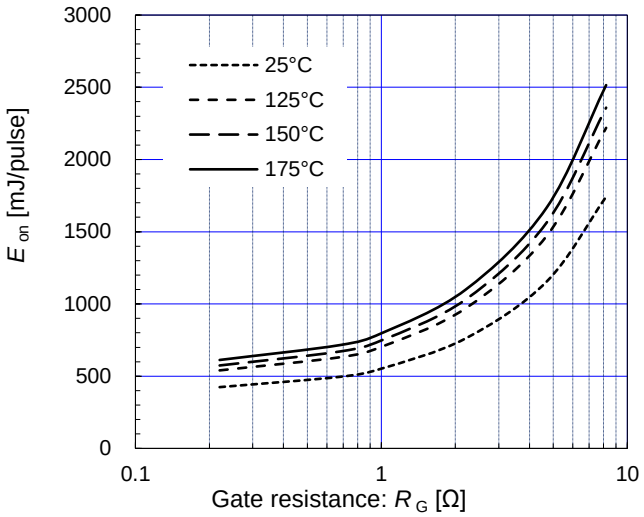
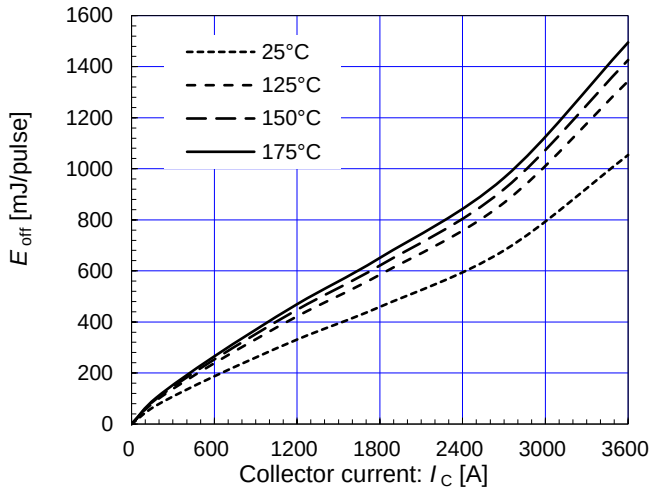
[Inverter]
E_{on} vs. Collector current (typ.)
V_{CC} = 900V, V_{GE} = ±15V, R_G = +0.22/-0.68Ω



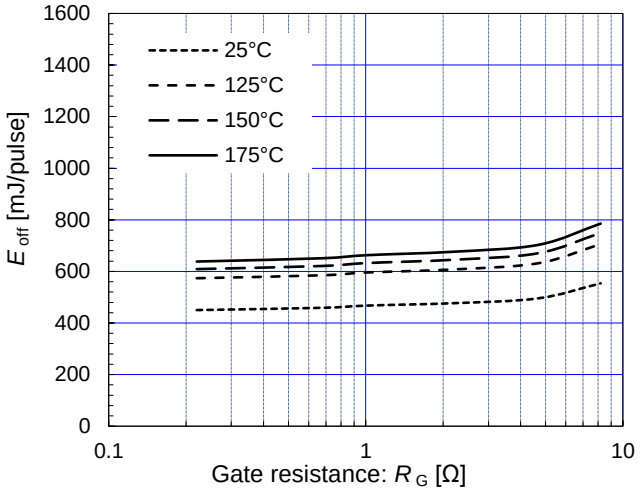
[Inverter]
E_{on} vs. Gate resistance (typ.)
V_{CC} = 900V, V_{GE} = ±15V, I_C = 1800A



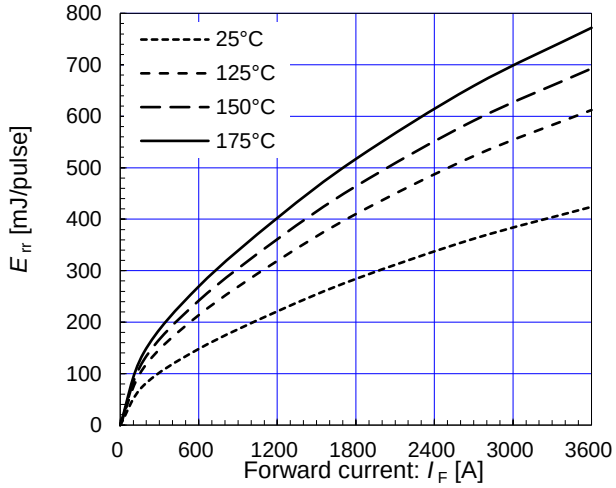
[Inverter]
E_{off} vs. Collector current (typ.)
V_{CC} = 900V, V_{GE} = ±15V, R_G = +0.22/-0.68Ω



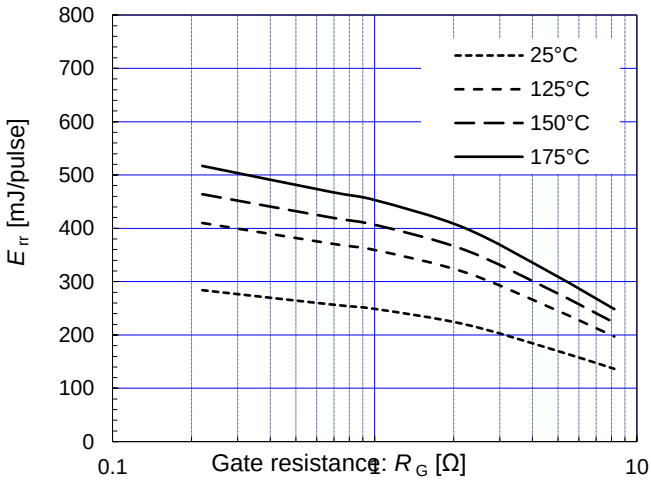
[Inverter]
E_{off} vs. Gate resistance (typ.)
V_{CC} = 900V, V_{GE} = ±15V, I_C = 1800A



[Inverter]
E_{rr} vs. Forward current (typ.)
V_{CC} = 900V, V_{GE} = ±15V, R_G = +0.22/-0.68Ω



[Inverter]
E_{rr} vs. Gate resistance (typ.)
V_{CC} = 900V, V_{GE} = ±15V, I_F = 1800A



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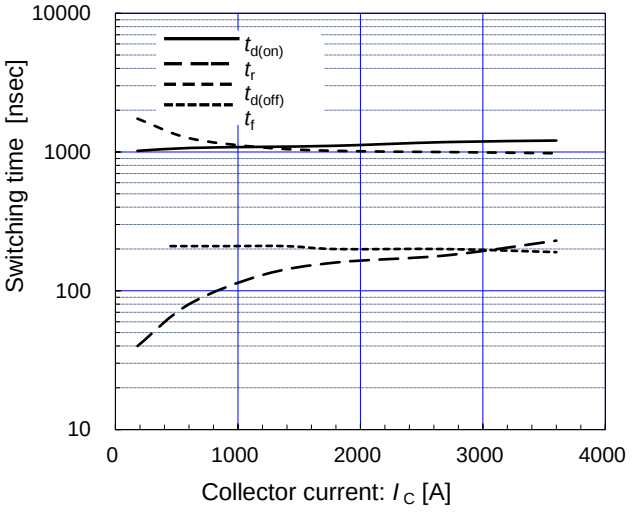
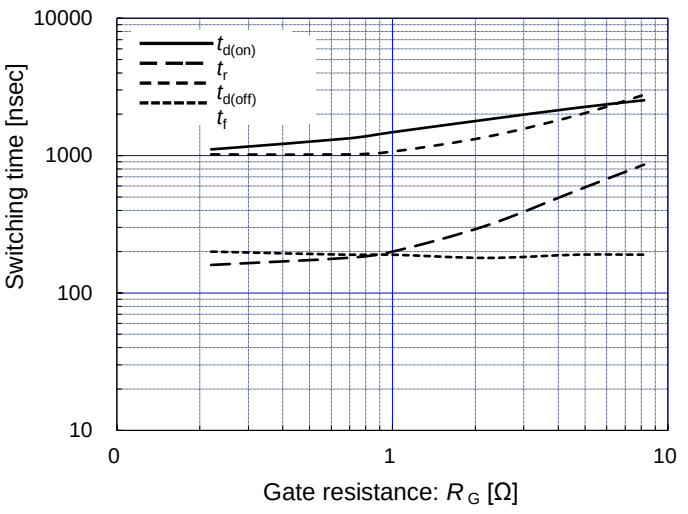
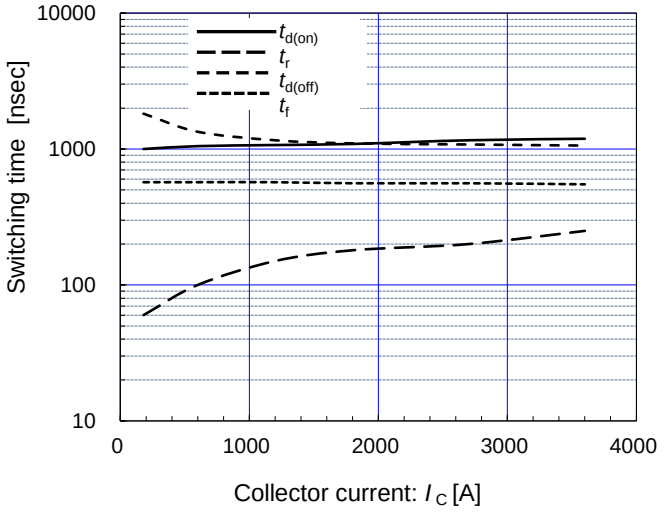
[Inverter]
Switching time vs. Collector current (typ.)
V_{CC} = 900V, R_G = +0.22/-0.68Ω V_{GE} = ±15V, T_{vj} = 25°C



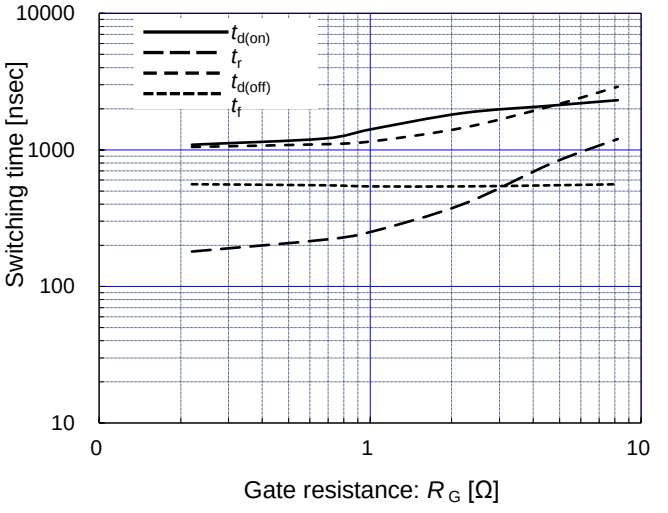
[Inverter]
Switching time vs. Gate resistance (typ.)
V_{CC} = 900V, I_C = 1800A, V_{GE} = ±15V, T_{vj} = 25°C



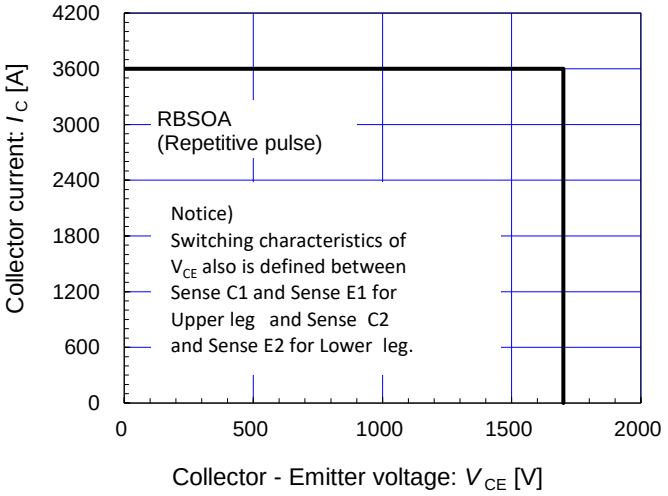
[Inverter]
Switching time vs. Collector current (typ.)
V_{CC} = 900V, R_G = +0.22/-0.68Ω V_{GE} = ±15V, T_{vj} = 175°C



[Inverter]
Switching time vs. Gate resistance (typ.)
V_{CC} = 900V, I_C = 1800A, V_{GE} = ±15V, T_{vj} = 175°C



[Inverter]
Reverse bias safe operating area (max.)
V_{GE} = ±15V, R_G = +0.22/-0.68Ω T_{vj} = 175°C



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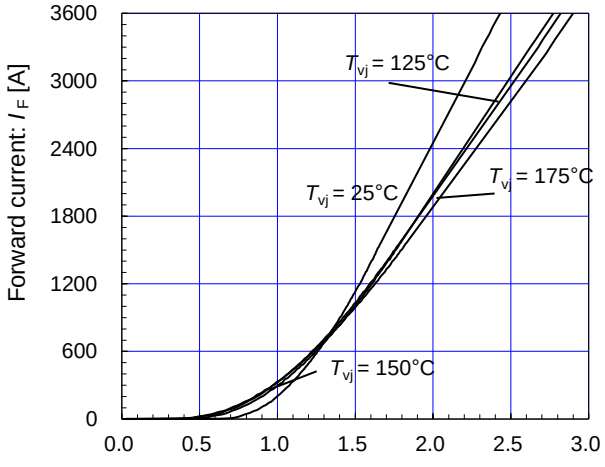
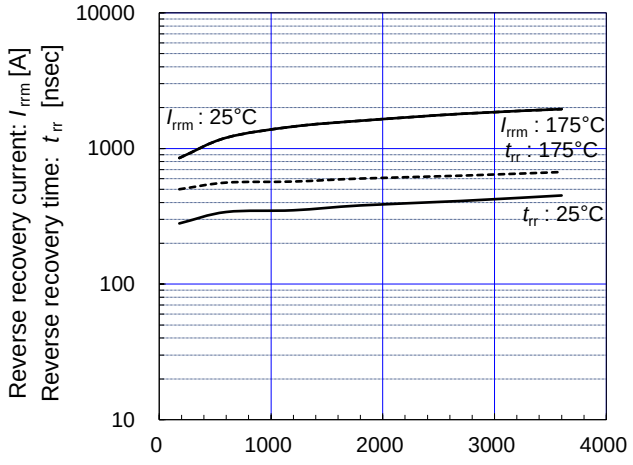
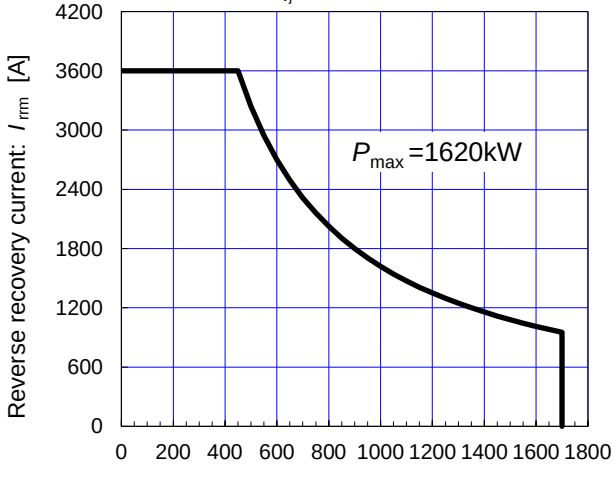
[Inverter]
Forward current vs. Forward voltage (typ.)
chip



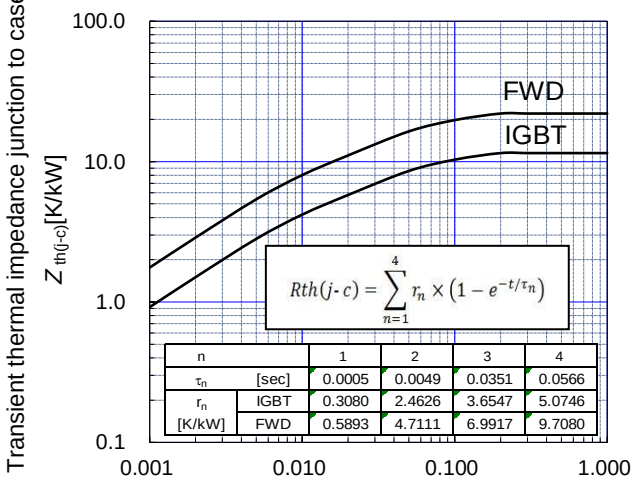
[Inverter]
Reverse recovery characteristics (typ.)
V_{CC} = 900V, V_{GE} = ±15V, R_G = +0.22/-0.68Ω



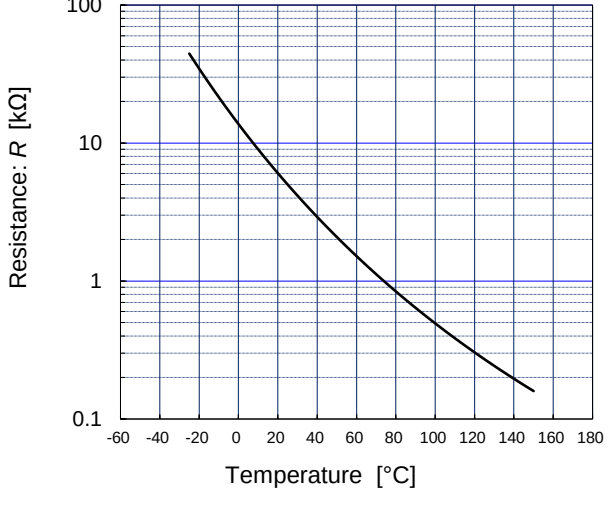
[Inverter]
FWD safe operation area (max.)
T_{vj} = 175°C



[Inverter]
Transient Thermal resistance (max.)



[Thermistor]
Temperature characteristic (typ.)



Warnings

1. This Catalog contains the product specifications, characteristics, data, materials, and structures as of 7/2019. The contents are subject to change without notice for specification changes or other reasons. When using a product listed in this Catalog, be sure to obtain the latest specifications.

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4. The products introduced in this Catalog are intended for use in the following electronic and electrical equipment which has normal reliability requirements.
・Computers ・OA equipment ・Communications equipment (terminal devices) ・Measurement equipment
・Machine tools ・Audiovisual equipment ・Electrical home appliances ・Personal equipment ・Industrial robots etc.

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・Transportation equipment (mounted on cars and ships) ・Trunk communications equipment
・Traffic-signal control equipment ・Gas leakage detectors with an auto-shut-off feature
・Emergency equipment for responding to disasters and anti-burglary devices ・Safety devices ・Medical equipment

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7.

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